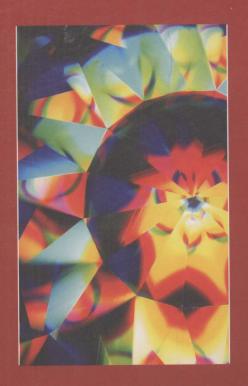
牛津大学 研究生教材系列

Optical Properties of Solids 固体的光学性质

M. Fox





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Optical Properties of Solids

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M. Fox

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Preface

This book is about the way light interacts with solids. The beautiful colours of gemstones have been valued in all societies, and metals have been used for making mirrors for thousands of years. However, the scientific explanations for these phenomena have only been given in relatively recent times. Nowadays, we build on this understanding and make use of rubies and sapphires in high power solid state lasers. Meanwhile, the arrival of inorganic and organic semiconductors has created the modern optoelectronics industry. The onward march of science and technology therefore keeps this perennial subject alive and active.

The book is designed for final year undergraduates and first year graduate students in physics. At the same time, I hope that some of the topics will be of interest to students and researchers of other disciplines such as engineering or materials science. It evolved from a final year undergraduate course in condensed matter physics given as part of the Master of Physics degree at Oxford University. In preparing the course I became aware that the discussion of optical phenomena in most of the general solid state texts was relatively brief. My aim in writing was therefore to supplement the standard texts and to introduce new subjects that have come to the fore in the last 10–20 years.

Practically all textbooks on this subject are built around a number of core topics such as interband transitions, excitons, free electron reflectivity, and phonon polaritons. This book is no exception. These core topics form the backbone for our understanding of the optical physics, and pave the way for the introduction of more modern topics. Much of this core material is well covered in the standard texts, but it can still benefit from the inclusion of more recent experimental data. This is made possible through the ever-improving purity of optical materials and the now widespread use of laser spectroscopy.

The overall plan of the subject material is summarized in Fig. 1. The flow diagram shows that some of the chapters can be read more or less independently of the others, on the assumption that the introductory material in Chapters 1 and 2 has been fully assimilated. I say 'more or less' here because it does not really make sense, for example, to try to understand nonlinear optics without a firm grasp of linear optics. The rest of the chapters have been arranged into groups, with their order following a certain logical progression. For example, knowledge of interband absorption is required to understand quantum wells, and is also needed to explain certain details in the reflectivity spectra of metals. Similarly, molecular materials provide an intuitive introduction to the concept of configuration diagrams, which are required for the understanding of colour centres and luminescent impurities.

The inclusion of recent developments in the subject has been one of the main priorities motivating this work. The chapters on semiconductor quantum

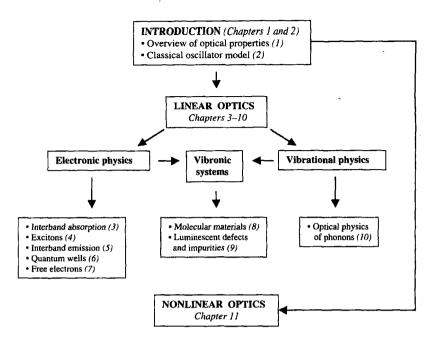


Fig. 1 Scheme of the subject topics covered in this book. The numbers in brackets refer to the chapters where the subject material is developed.

wells, molecular materials, and nonlinear optics will not be found in most of the standard texts. Other new topics such as the Bose-Einstein condensation of excitons are included alongside traditional subject material. Furthermore, it is my deliberate intention to illustrate the physics with up-to-date examples of optical technology. This provides an interesting modern motivation for traditional topics such as colour centres and also helps to emphasize the importance of the solid state devices.

Throughout the book I have understood the term 'optical' in a wider sense than its strict meaning referring to the visible spectral region. This has allowed me to include discussions of infrared phenomena such as those due to phonons and free carriers, and also the properties of insulators and metals in the ultraviolet. I have likewise taken the scope of the word 'solid' beyond the traditional emphasis on crystalline materials such as metals, semiconductors and insulators. This has allowed me to include both 'soft condensed matter' materials, such as polymers, and also glasses, which are not solids in the strict sense.

The process of relating measured optical phenomena to the electronic and vibrational properties of the material under study can proceed in two ways. We can work forwards from known electronic or vibrational physics to predict the results of optical experiments, or we can work backwards from experimental data to the microscopic properties. An example of the first approach is to use the free electron theory to explain why metals reflect light, while an example of the second is to use absorption or emission data to deduce the electron level structure of a crystal. Textbooks such as this one inevitably tend to work forwards from the microscopic properties to the measured data, even though an experimental scientist would probably be working in the other direction.

The book presupposes that the reader has a working knowledge of solid state physics at the level appropriate to a third year undergraduate, such as that found in H.M. Rosenberg's *The Solid State* (Oxford University Press, third

edition, 1988). This puts the treatment at about the same as, or at a slightly higher level, than that given in the Introduction to Solid State Physics by Charles Kittel. The book also necessarily presupposes a reasonable knowledge of electromagnetism and quantum theory. Classical and quantum arguments are used interchangeably throughout, and the reader will need to revise their own favourite texts on these subjects if any of the material is unfamiliar. Three appendices are included to provide a succinct summary of the principal results from band theory, electromagnetism and quantum theory that are presupposed.

The text has been written in a tutorial style, with worked examples in most chapters. A collection of exercises is provided at the end of each chapter, with solutions at the end of the book. The exercises follow the presentation of the material in the chapter, and the more challenging ones are identified with an asterisk.

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Numerous colleagues have helped to clarify my understanding of certain specialist topics and have made comments on the text. Among these I would like to single out Dr Simon Martin and Dr Paul Lane for their critical reading of the chapter on molecular materials. I am, of course, grateful to my teachers, who enthused me with the subject, and to the students who have taken the course and tried out some of the problems.

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Introduction

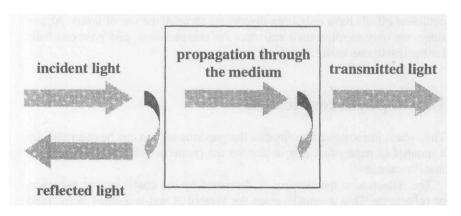
Light interacts with matter in many different ways. Metals are shiny, but water is transparent. Stained glass and gemstones transmit some colours, but absorb others. Other materials such as milk appear white because they scatter the incoming light in all directions.

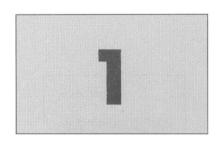
In the chapters that follow, we will be looking at a whole host of these optical phenomena in a wide range of solid state materials. Before we can begin to do this, we must first describe the way in which the phenomena are classified, and the coefficients that are used to quantify them. We must then introduce the materials that we will be studying, and clarify in general terms how the solid state is different from the gas and liquid phase. This is the subject of the present chapter.

1.1 Classification of optical processes

The wide-ranging optical properties observed in solid state materials can be classified into a small number of general phenomena. The simplest group, namely reflection, propagation and transmission, is illustrated in Fig. 1.1. This shows a light beam incident on an optical medium. Some of the light is reflected from the front surface, while the rest enters the medium and propagates through it. If any of this light reaches the back surface, it can be reflected again, or it can be transmitted through to the other side. The amount of light transmitted is therefore related to the reflectivity at the front and back surfaces and also to the way the light propagates through the medium.

The phenomena that can occur while light propagates through an optical medium are illustrated schematically in Fig. 1.2.





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Fig. 1.1 Reflection, propagation and transmission of a light beam incident on an optical medium.

Fig. 1.2 Phenomena that can occur as a light beam propagates through an optical medium. Refraction causes a reduction in the velocity of the wave, while absorption causes attenuation. Luminescence can accompany absorption if the excited atoms re-emit by spontaneous emission. Scattering causes a redirection of the light. The diminishing width of the arrow for the processes of absorption and scattering represents the attenuation of the beam.

Refraction causes the light waves to propagate with a smaller velocity than in free space. This reduction of the velocity leads to the bending of light rays at interfaces described by Snell's law of refraction. Refraction, in itself, does not affect the intensity of the light wave as it propagates.

Absorption occurs during the propagation if the frequency of the light is resonant with the transition frequencies of the atoms in the medium. In this case, the beam will be attenuated as it progresses. The transmission of the medium is clearly related to the absorption, because only unabsorbed light will be transmitted. Selective absorption is responsible for the colouration of many optical materials. Rubies, for example, are red because they absorb blue and green light, but not red.

Luminescence is the general name given to the process of spontaneous emission of light by excited atoms in a solid state material. One of the ways in which the atoms can be promoted into excited states prior to spontaneous emission is by the absorption of light. Luminescence can thus accompany the propagation of light in an absorbing medium. The light is emitted in all directions, and has a different frequency to the incoming beam.

Luminescence does not always have to accompany absorption. It takes a characteristic amount of time for the excited atoms to re-emit by spontaneous emission. This means that it might be possible for the excited atoms to dissipate the excitation energy as heat before the radiative re-emission process occurs. The efficiency of the luminescence process is therefore closely tied up with the dynamics of the de-excitation mechanisms in the atoms.

Scattering is the phenomenon in which the light changes direction and possibly also its frequency after interacting with the medium. The total number of photons is unchanged, but the number going in the forward direction decreases because light is being re-directed in other directions. Scattering therefore has the same attenuating effect as absorption. The scattering is said to be elastic if the frequency of the scattered light is unchanged, or inelastic if the frequency changes in the process. The difference in the photon energy in an inelastic scattering process has to be taken from the medium if the frequency increases or given to the medium if the frequency decreases.

A number of other phenomena can occur as the light propagates through the medium if the intensity of the beam is very high. These are described by nonlinear optics. An example is frequency doubling, in which the frequency of part of a beam is doubled by interaction with the optical medium. These nonlinear effects have only been discovered through the use of lasers. At this stage, we only mention their existence for completeness, and postpone their further discussion until Chapter 11.

1.2 Optical coefficients

The optical phenomena described in the previous section can be quantified by a number of parameters that determine the properties of the medium at the macroscopic level.

The reflection at the surfaces is described by the coefficient of reflection or reflectivity. This is usually given the symbol R and is defined as the ratio of the reflected power to the power incident on the surface. The coefficient